

VN460SP

SINGLE CHANNEL HIGH SIDE SMART SOLID STATE RELAY

TYPE	V _{demag}	R _{DS(on)}	IOUT	Vcc
VN460SP	V_{CC} -55V	20 m Ω	25 A	36 V

- OUTPUT CURRENT (CONTINUOUS): 25 A @ $T_C = 25$ ° C
- 5 V LOGIC LEVEL COMPATIBLE INPUT
- UNDER VOLTAGE SHUT-DOWN
- OVER VOLTAGE SHUT-DOWN
- THERMAL SHUT-DOWN
- OPEN DRAIN DIAGNOSTIC OUTPUT
- VERY LOW STAND-BY POWER DISSIPATION

DESCRIPTION

The VN460SP is a monolithic device made using SGS-THOMSON Vertical Intelligent Power Technology, intended for driving resistive or inductive loads with one side connected to ground.

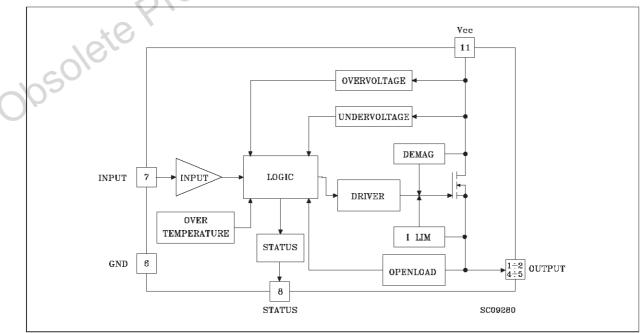
Built-in thermal shut-down protects the chip from over temperature and short circuit.

Power SO-10TM

The control input is 5V CMOS logic level compatible.

The open drain diagnostic output indicates open circuit (no load) and overtemperature status.

BLOCK DIAGRAM

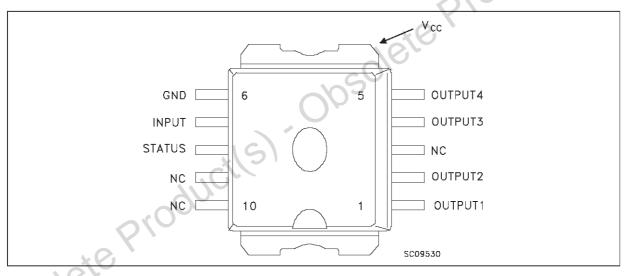


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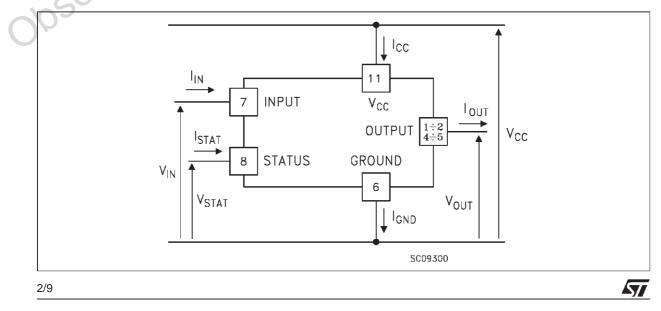
ABSOLUTE MAXIMUM RATING

Symbol	Parameter	Value	Unit
Vcc	Power Supply Voltage (continuous)	45	V
-Vcc	Reverse Supply Voltage (continuous)	-0.3	V
IOUT	Output Current (continuous)	Internally Limited	A
I _R	Reverse Output Current	-25	A
lin	Input Current	±10	mA
ISTAT	Status Pin Current	±10	mA
-I _{GND}	Reverse Ground Current	-200	mA
Vesd	Electrostatic Discharge (1.5 kΩ, 100 pF)	2000	V
Ptot	Power Dissipation at $T_c \le 25$ °C	112	W
Tj	Junction Operating Temperature	-40 to 150	P°C
Tstg	Storage Temperature	-55 to 150	°C
		oroduc	

CONNECTION DIAGRAM



CURRENT AND VOLTAGE CONVENTIONS



ELECTRICAL TRANSIENTS REQUIREMENTS

ISO T/R 7637/1	TEST LEVELS						
Test Pulse	I	П	111	IV	Delays and Impedance		
1	-25 V	-50 V	-75 V	-100 V	2 ms, 10 Ω		
2	+25 V	+50 V	+75 V	+100 V	0.2 ms, 10 Ω		
3a	-25 V	-50 V	-100 V	-150 V	0.1 μs, 50 Ω		
3b	+25 V	+50 V	+75 V	+100 V	0.1 μs, 50 Ω		
4	-4 V	-5 V	-6 V	-7 V	100 ms, 0.01 Ω		
5	+26.5	+46.5	+66.5	+86.5	400 ms, 2 Ω		
					JUCT(S)		

ISO T/R 7637/1	TES	ST LEVELS RESU	LTS	000	
Test Pulse	I	П	111	IV	
1	С	С	С	С	
2	С	С	С	С	
3a	С	С	C	С	
3b	С	С	С	С	
4	С	С	С	С	
5	С	E	E	E	

(With a series resistor $\ge 1 \text{ K}\Omega$ in input and status pins).

CLASS	CONTENTS
С	All function of the device are performed as designed after exposure to disturbance.
E	One or more functions of the device is not performed as designed after exposure and cannot be returned to proper operation without replacing the device.
2105010	

THERMAL DATA

R _{thj-case}	Thermal Resistance Junction-case	Max	1.1	°C/W			
R _{thj-a(*)}	Thermal Resistance Junction-ambient	Max	50	°C/W			
(+) \//hop mou	When mounted using minimum recommended and size on EP 4 board						

(*) When mounted using minimum recommended pad size on FR-4 board.

ELECTRICAL CHARACTERISTICS (V_{CC} = 13 V; -40 $^{\circ}$ C < T_J < 125 $^{\circ}$ C unless otherwise specified) POWER

Symbol	Parameter	Test (Conditions	Min.	Тур.	Max.	Unit
Vcc	Operating Supply Voltage			5.5	13	36	V
V_{usd}	Under Voltage Shut Down			3	4	5.5	SY
Vov	Overvoltage Shut Down			36	39	45	V
Ron	On State Resistance	I _{OUT} = 5 A I _{OUT} = 5 A	T _J = 25 °C		9,	20 36	mΩ mΩ
Is	Supply Current	Off state On State	$T_{Case} = 25 \ ^{\circ}C$	21	15 1.4	30 3.3	μA mA
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LOGIC INPUT

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
VIL	Input Low Level Voltage	(*)			1.5	V
VIH	Input High Level Voltage (see note 1)	(*)	3.5			V
V _{I(hyst.)}	Input Hysteresis Voltage		0.2	0.85	1.5	V
I _{IN}	Input Current	$V_{IN} = 5 V$ $T_{case} = 25 °C$			100	μΑ
VICL	Input Clamp Voltage	I _{IN} = 10 mA I _{IN} = -10 mA	5	6 -0.7	7	V V

(*) : The input voltage is internally clamped at 6 V about. It is possible to connect this pin to an higher voltage via an external resistor provided the input current does not exceed 10 mA.

SWITCHING (Vcc = 13 V)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
t _{d(on)}	Turn-on Delay Time Of Output Current	$I_{OUT} = 5 A$ Resistive Load Input Rise Time < 0.1 μ s T _j = 25 °C	25	90	250	μs
tr	Rise Time Of Output Current	$I_{OUT} = 5 A$ Resistive Load Input Rise Time < 0.1 μ s T _j = 25 °C	80	300	650	μs
t _{d(off)}	Turn-off Delay Time Of Output Current	$I_{OUT} = 5 A$ Resistive Load Input Rise Time < 0.1 μ s T _j = 25 °C	300	750	1500	μs
t _f	Fall Time Of Output Current	$I_{OUT} = 5 A$ Resistive Load Input Rise Time < 0.1 μ s T _j = 25 °C	80	200	400	μs
(di/dt) _{on}	Turn-on Current Slope	I _{OUT} = 5 A		0.02	0.05	A/μs
(di/dt) _{off}	Turn-off Current Slope	I _{OUT} = 5 A		0.02	0.05	A/μs

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ELECTRICAL CHARACTERISTICS (continued)

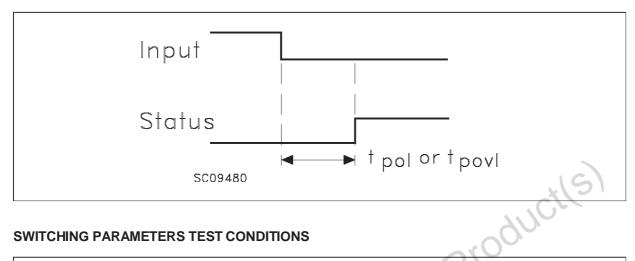
PROTECTIONS AND DIAGNOSTICS

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
T _{TSD}	Thermal Shut-down Temperature		150	170	190	°C
T_{TR}	Thermal Reset Temperature		135			°C
T _{RSD} (HYST)	Thermal Hysteresis		5	15	50	°C
V _{ENOL}	Output Voltage Authorizing Openload Detection	8V≤V _{CC} ≤30V	5.2	6.6	8	V
I _{OL}	Open Load Current Level	8V≤V _{CC} ≤30V	100	800	1500	mA
I _{OV}	Over Current	$R_{LOAD} \le 10 m\Omega$ - 40°C <t<sub>Case<125°C</t<sub>	25	50	<u>}</u>	A
I _{AV}	Average Current in Short Circuit	$ \begin{array}{l} R_{LOAD} \leq \! 10 \ m\Omega \\ T_{C} = 85^{\circ}C \end{array} $	25	5.4		A
V _{STAT}	Status Output Voltage	I _{STAT} = 1.6 mA (Fault Condition)	1		0.4	V
V _{SCL}	Status Clamp Voltage	I _{STAT} = 10 mA I _{STAT} = -10 mA	5.5	6 -0.7	7	V V
t _{POL}	Status Delay	(*)	50	300	950	μs
tpovl	Status Delay	(*)			10	μs
Vdemag	Turn-off Output Clamp Voltage	$I_{OUT} = 5 \text{ A}, L = 1 \text{ mH}, V_{IN} = 0$	V _{CC} -45	V _{cc} -50	V _{CC} -55	V

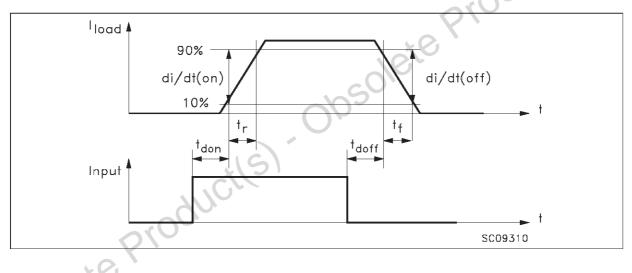
(*) ISO definitions T_{POL} = Status delay in case of open load conditions T_{POVL} = Status delay in case of over load conditions ase of ay in case of consolete Proof



FIGURE 1



SWITCHING PARAMETERS TEST CONDITIONS



TRUTH TABLE

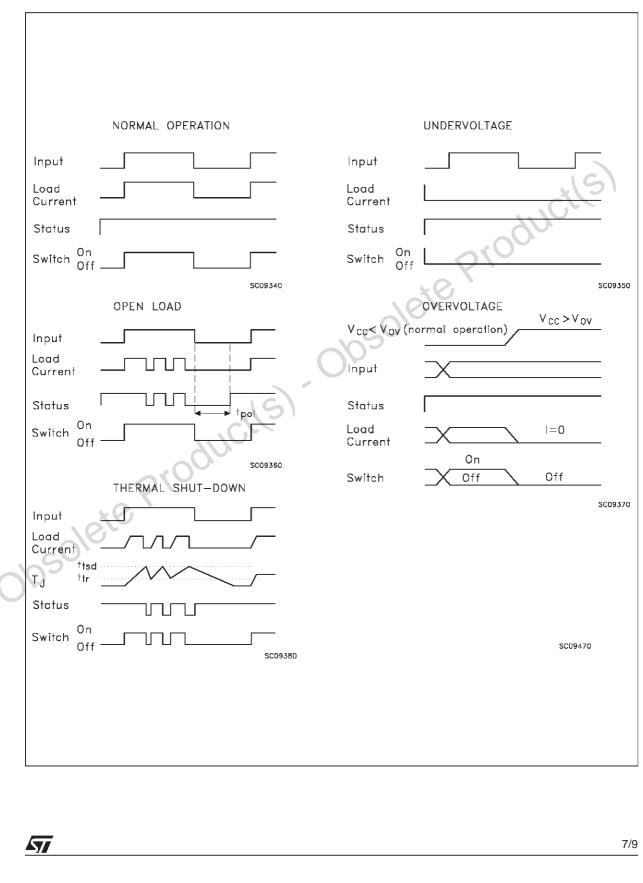
Conditions	INPUT	OUTPUT	STATUS
Normal Operation	L H	L H	H H
Over-voltage	X	L	Н
Under-voltage	X	L	Н
Thermal shut-down	н	L	L
Open load	Н	Н	L

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H = high level, L= low level, X= unspecified

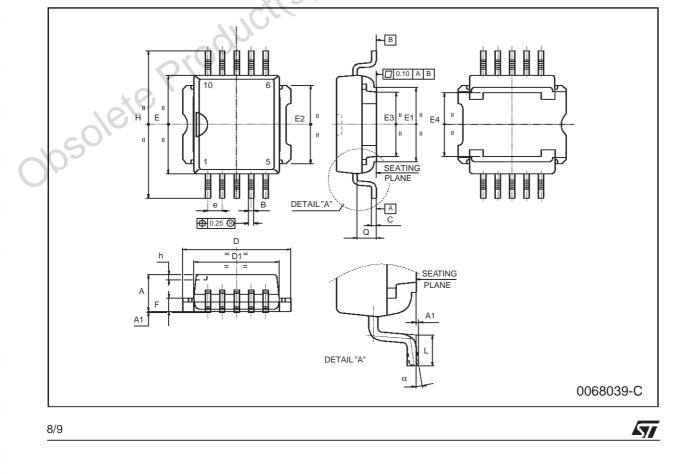
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VN460SP

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А	3.35		3.65	0.132		0.144
A1	0.00		0.10	0.000		0.004
В	0.40		0.60	0.016		0.024
С	0.35		0.55	0.013		0.022
D	9.40		9.60	0.370		0.378
D1	7.40		7.60	0.291		0.300
E	9.30		9.50	0.366		0.374
E1	7.20		7.40	0.283		0.291
E2	7.20		7.60	0.283	6	0.300
E3	6.10		6.35	0.240	~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	0.250
E4	5.90		6.10	0.232		0.240
е		1.27		× 0,	0.050	
F	1.25		1.35	0.049		0.053
Н	13.80		14.40	0.543		0.567
h		0.50		2	0.002	
L	1.20		1.80	0.047		0.071
q		1.70			0.067	
α	0°		8°			



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